

isc N-Channel MOSFET Transistor

IPD65R650CE,IIPD65R650CE

FEATURES

Static drain-source on-resistance:

R⊳s(on)≤0.65Ω

- Enhancement mode:
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRITION

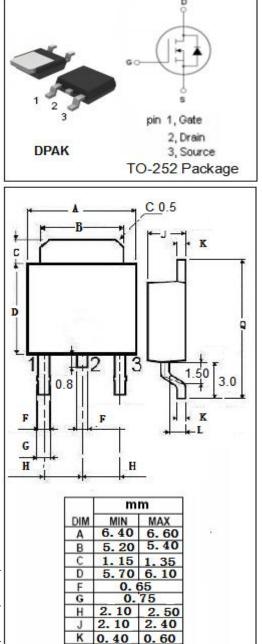
- · Fast switching
- Very high commutation ruggedness

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	650	V
V _{GS}	Gate-Source Voltage	±20	V
ID	Drain Current-Continuous	10.1	А
I _{DM}	Drain Current-Single Pulsed	18	A
PD	Total Dissipation @T _c =25°C	86	W
Tj	Max. Operating Junction Temperature	150	°C
T _{stg}	Storage Temperature	-40~150	°C

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
Rth(j-c)	Channel-to-case thermal resistance 1.		°C/W
Rth(j-a)	Channel-to-ambient thermal resistance	62	°C /W



L

0

0.90

9.90

1.10

10.



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ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D =1mA	650			V
V _{GS} (th)	Gate Threshold Voltage	VDS=VGS; ID=0.21mA	2.5		3.5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V; I _D =2.1A			0.65	Ω
I _{GSS}	Gate-Source Leakage Current	V _{GS} =20V; V _{DS} =0V			0.1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} =650V; V _{GS} = 0V			1	μ Α
V _{SD}	Diode forward voltage	I _F =3.2A, V _{GS} = 0V		0.9		V

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